

EAST: (10081816 asymmetric intergate insulby /AID.rep.1)

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162:162213 with 61
 163:1722150 with 61
 164:1216162 same 63
 165:1276676171 (ad & pdi <"20010030"
 166:1126184 and 65
 167:1459911 graded
 168:1415711 (aluminum adj oxide "al.sub.20.sub.3" al2o3 AlO alumina)
 169:1222167 near 6 66
 170:12169 near 6 2
 171:1812 near 6 67
 172:1602123 near 6 68
 173:1181905912 35
 174:143172 same 73
 175:143174 same 68
 176:138175 not 40
 177:130178 and 65
 178:11791281 (aluminum adj oxide "al.sub.20.sub.3" al2o3 AlO)
 179:156178 near 9 2
 180:18179 and 65
 181:17179 with 12 531
 182:1111178 same 12 531
 183:13182 and 65
 184:19881 srtio
 185:16178 near 9 64
 186:17178 with 84

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April 2005

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	U	1	Inventor	Document	Issue	P	Title	Current	Current	Retrieval	S	C	P	3	Image	Def
1			Demkov, Ale	US 200400	2004	6	Semiconductor device structures whic	257/411	257/429.1							US 20040
2			Hoshino, Ka	US 200200	2002	2	Magnetoresistive head, producing me	366/82	366/319;							US 20020
3			Shinkawat	US 200200	2002	2	Semiconductor device and method of	257/774	257/121.5							US 20020
4			Demkov, Al	US 6791125	2004	6	Semiconductor device structures whic	257/19	257/408;							US 679112
5			HOSHINO, KA	JP 2002197	2002	12	MAGNETO-RESISTANCE EFFECT HEAD, ITS									JP 200219
6			UZUMAKI, TA	JP 0518621	1993	3	PRODUCTION OF SUPERCONDUCTOR THIR	505/470								JP 051862
7				JP 5903050	1994	5	Optical circuit baseplate - has substrat									JP 590305

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